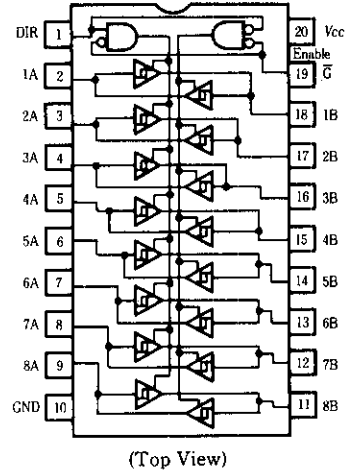


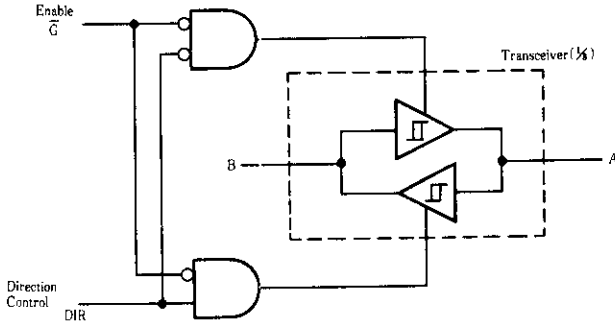
HD74LS645 ● Octal Bus Transceivers (non-inverted 3-state outputs)

This octal bus transceiver is designed for asynchronous two-way communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus depending upon the level at the direction control (DIR) input. The enable input (\bar{G}) can be used to disable the device so that the buses are effectively isolated.

■ PIN ARRANGEMENT



■ BLOCK DIAGRAM



■ RECOMMENDED OPERATING CONDITIONS

Item	Symbol	min	typ	max	unit
Supply voltage	V_{CC}	4.75	5.00	5.25	V
Output current	I_{OH}	—	—	-15	mA
Output current	I_{OL}	—	—	24	mA
Operating temperature range	T_{opr}	-20	25	75	°C

■ FUNCTIONAL TABLE

Enable \bar{G}	Direction Control DIR	Operation
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

H; high level,
L; low level,
X; irrelevant

HD74LS645

■ ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^\circ\text{C}$)

Item	Symbol	Test Conditions		min	typ*	max	Unit
Input voltage	V_{IH}			2.0			V
	V_{IL}			—	—	0.8	
Hysteresis	$V_T^+ - V_T^-$	$V_{CC} = 4.75\text{V}$		0.2	—	—	V
Output voltage	V_{OH}	$V_{CC} = 4.75\text{V}, V_{IH} = 2\text{V},$ $V_{IL} = 0.8\text{V}$	$I_{OH} = -3\text{mA}$	2.4	—	—	V
			$I_{OH} = -15\text{mA}$	2	—	—	
	V_{OL}	$V_{CC} = 4.75\text{V}, V_{IH} = 2\text{V},$ $V_{IL} = 0.8\text{V}$	$I_{OL} = 12\text{mA}$	—	—	0.4	V
			$I_{OL} = 24\text{mA}$	—	—	0.5	
Output current	I_{OZH}	$V_{CC} = 5.25\text{V}$	$V_O = 2.7\text{V}$	—	—	20	μA
	I_{OZL}	\bar{G} input = 2V	$V_O = 0.4\text{V}$	—	—	-400	
Input current	I_{IH}	$V_{CC} = 5.25\text{V}, V_I = 2.7\text{V}$		—	—	20	μA
	I_{IL}	$V_{CC} = 5.25\text{V}, V_I = 0.4\text{V}$		—	—	-400	μA
	A or B	$V_{CC} = 5.25\text{V}$	$V_I = 5.5\text{V}$	—	—	0.1	mA
	DIR or \bar{G}		$V_I = 7\text{V}$	—	—	0.1	
Short-circuit output current	I_{OS}^{***}	$V_{CC} = 5.25\text{V}$		-40	—	-225	mA
Supply current **	I_{CCH}	$V_{CC} = 5.25\text{V}, \text{OUTPUT OPEN}$		—	48	70	mA
	I_{CCL}			—	62	90	
	I_{CCZ}			—	64	95	
Input clamp voltage	V_{IK}	$V_{CC} = 4.75\text{V}, I_{IN} = -18\text{mA}$		—	—	-1.5	V

* $V_{CC} = 5\text{V}, T_a = 25^\circ\text{C}$

** I_{CC} is measured with all outputs open.

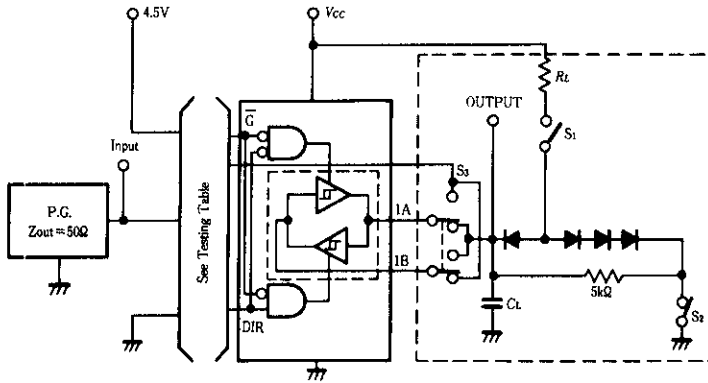
*** Not more than one output should be shorted at a time, duration of short-circuit should not exceed one second.

■ SWITCHING CHARACTERISTICS ($V_{CC} = 5\text{V}, T_a = 25^\circ\text{C}$)

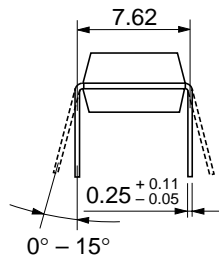
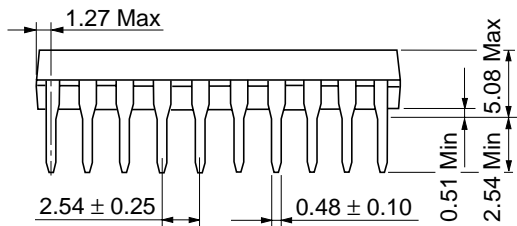
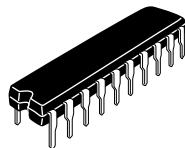
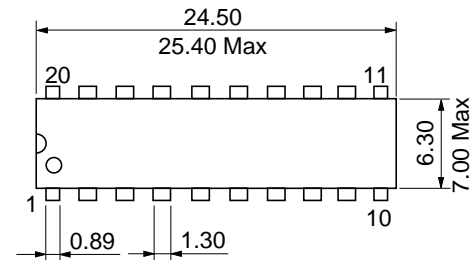
Item	Symbol	Input	Output	Test Condition	min	typ	max	Unit
Propagation delay time	t_{PLH}	A	B	$C_L = 45\text{pF},$ $R_L = 667\ \Omega$	—	8	15	ns
		B	A		—	8	15	ns
	t_{PHL}	A	B		—	11	15	ns
		B	A		—	11	15	ns
Output enable time	t_{ZL}	\bar{G}	A		—	31	40	ns
		\bar{G}	B		—	31	40	ns
	t_{ZH}	\bar{G}	A		—	26	40	ns
		\bar{G}	B		—	26	40	ns
Output disable time	t_{LZ}	\bar{G}	A	$C_L = 5\text{pF},$ $R_L = 667\ \Omega$	—	15	25	ns
		\bar{G}	B		—	15	25	ns
	t_{HZ}	\bar{G}	A		—	15	25	ns
		\bar{G}	B		—	15	25	ns

TESTING METHOD

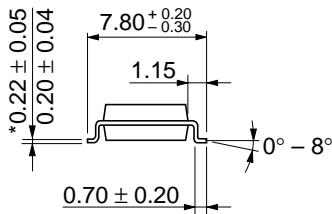
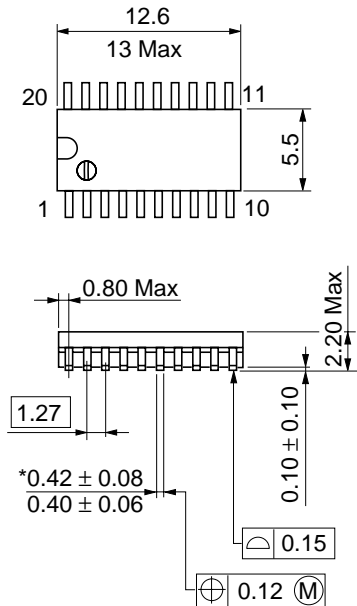
Test Circuit



- Notes)
1. C_L includes probe and jig capacitance.
 2. All diodes are 1S2074 $\text{\textcircled{H}}$.
 3. 2A-2B, 3A-3B, 4A-4B, 5A-5B, 6A-6B, 7A-7B, 8A-8B are identical to above load circuit.
 4. S_2 is an input-output switch.

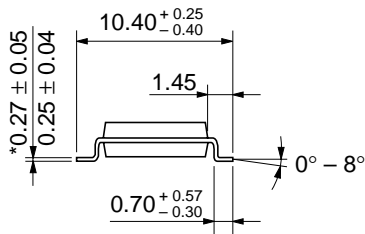
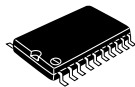
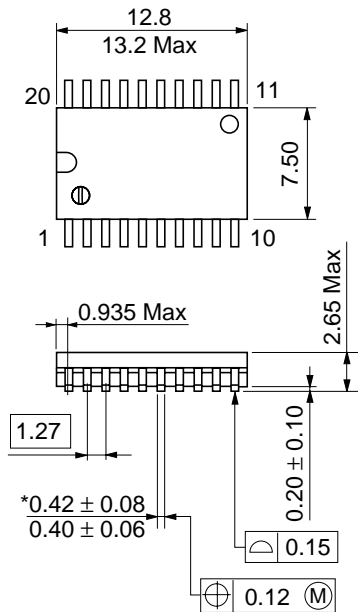


Hitachi Code	DP-20N
JEDEC	—
EIAJ	Conforms
Weight (reference value)	1.26 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.31 g



Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	—
Weight (reference value)	0.52 g

*Dimension including the plating thickness
 Base material dimension

Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL North America : <http://semiconductor.hitachi.com/>
 Europe : <http://www.hitachi-eu.com/hel/ecg>
 Asia (Singapore) : <http://www.has.hitachi.com.sg/grp3/sicd/index.htm>
 Asia (Taiwan) : http://www.hitachi.com.tw/E/Product/SICD_Frame.htm
 Asia (HongKong) : <http://www.hitachi.com.hk/eng/bo/grp3/index.htm>
 Japan : <http://www.hitachi.co.jp/Sicd/indx.htm>

For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe GmbH
Electronic components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 049318
Tel: 535-2100
Fax: 535-1533

Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building, No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281
Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.

HITACHI